

IPW

**PATENT APPLICATION**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Masahiro SAKURADA et al.

Group Art Unit: 1722

Application No.: 10/561,205

Examiner: F. HITESHEW

Filed: February 3, 2006

Docket No.: 126342

For: A METHOD FOR PRODUCING A SINGLE CRYSTAL AND A SINGLE CRYSTAL

**COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

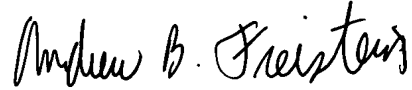
Sir:

In reply to the Examiner's Statement of Reasons for Allowance in the Notice of Allowance mailed September 21, 2007, please consider the following remarks.

The Examiner's Statement of Reasons for Allowance does not exactly correspond to independent claim 10, or any of the other allowed claims. Specifically, in the Notice of Allowance on page 3, line 4, after "portion of the crystal" the Reasons for Allowance should have stated "and the temperature gradient  $G_e$  of the crystal at the peripheral portion of the crystal." Additionally, in line 6, "thereby G" should be "thereby  $\Delta G$ ." Applicants respectfully request a corrected or supplemental Notice of Allowance with the indicated corrections.

The Examiner is invited to contact the undersigned at the telephone number set forth below regarding any matter concerning this application.

Respectfully submitted,



William P. Berridge  
Registration No. 30,024

Andrew B. Freistein  
Registration No. 52,917

JAO:ABF/hms

Date: November 5, 2007

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**Telephone: (703) 836-6400**

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